查询BT139B-500H供应商

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Philips Semiconductors

high noise immunity

GENERAL DESCRIPTION

suitable

Glass passivated triacs in a plastic

applications requiring high noise immunity in addition to high,

capability and thermal cycling performance. Typical applications include motor control, industrial lighting, heating and static switching.

blocking

DESCRIPTION

for surface

voltage

intended for use in

QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	MAX.	MAX.	UNIT
V _{DRM}	BT139B- Repetitive peak off-state voltages RMS on-state current	500H 500	600H 600 16	800H 800 16	V
I _{TSM}	Non-repetitive peak on-state current	140	140	140	Â

PIN CONFIGURATION

-D-2

3

1

SYMBOL



Product specification

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LIMITING VALUES

gate

PINNING - SOT404

main terminal 1

main terminal 2

main terminal 2

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	WW	MAX.		UNIT
V _{DRM}	Repetitive peak off-state voltages	515P	-	-500 500 ¹	-600 600 ¹	-800 800	V
I _{T(RMS)} I _{TSM}	RMS on-state current Non-repetitive peak on-state current	full sine wave; $T_{mb} \le 99$ °C full sine wave; $T_j = 25$ °C prior to surge	-		16		A
- 92		t = 20 ms t = 16.7 ms	-		140 150		A
l ² t	I ² t for fusing	t = 10.7 ms	-		98		A A ² s
dl _⊤ /dt	Repetitive rate of rise of on-state current after	$I_{TM} = 20 \text{ A}; I_G = 0.2 \text{ A}; dI_G/dt = 0.2 \text{ A}/\mu \text{s}$	-	B-			5A
	triggering	T2+ G+ T2+ G- T2- G- T2- G- T2- G+	15	WW	50 50 50 10		A/μs A/μs A/μs A/μs
I _{GM} V _{GM} P _{GM}	Peak gate current Peak gate voltage Peak gate power	SC.COM	- -		2 5 5		A V W
P _{G(AV)} T _{stg} T _j	Average gate power Storage temperature Operating junction temperature	over any 20 ms period	-40 -		0.5 150 125		°C ℃ ℃

Athough not recommended, off-state voltages up to 800V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 15 A/µs.

envelope

mounting,

PIN

1

2

3

mb

bidirectional

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THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-mb} R _{th j-a}	Thermal resistance junction to mounting base Thermal resistance junction to ambient	full cycle half cycle minimum footprint, FR4 board	- -	- - 55	1.2 1.7 -	K/W K/W K/W

STATIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS		MIN.	TYP.	MAX.	UNIT
I _{GT}	Gate trigger current	$V_{\rm D} = 12 \text{ V}; I_{\rm T} = 0.1 \text{ A}$					
01			T2+ G+	10	14	50	mA
			T2+ G-	10	17	50	mA
			T2- G-	10	18	50	mA
			T2- G+	10	40	100	mA
l IL	Latching current	$V_{\rm D} = 12 \text{ V}; \text{ I}_{\rm GT} = 0.1 \text{ A}$					
	_		T2+ G+	-	10	60	mA
			T2+ G-	-	25	90	mA
			T2- G-	-	12	60	mA
			T2- G+	-	14	90	mA
I I _H	Holding current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$		-	8	60	mA
Ϋ _T	On-state voltage	$I_{T} = 20 \text{ A}$		-	1.2	1.6	V
V _{GT}	Gate trigger voltage	$V_{\rm D} = 12 \text{ V}; \text{ I}_{\rm T} = 0.1 \text{ A}$		-	0.7	1.5	V
		V _D = 400 V; I _T = 0.1 A; T _i = 125 °	C	0.25	0.4	-	V
I _D	Off-state leakage current	$V_{\rm D} = V_{\rm DRM(max)}; T_{\rm j} = 125 \ ^{\circ}{\rm C}$		-	0.1	0.5	mA

DYNAMIC CHARACTERISTICS

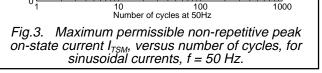
 $T_i = 25$ °C unless otherwise stated

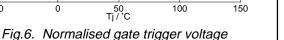
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
dV _D /dt	Critical rate of rise of off-state voltage	$V_{DM} = 67\% V_{DRM(max)}; T_j = 125 °C;$ exponential waveform; gate open circuit	200	500	-	V/µs
dV _{com} /dt	Critical rate of change of commutating voltage	$V_{DM} = 400 \text{ V}; \text{ T}_{j} = 95 \text{ °C}; \text{ I}_{T(RMS)} = 16 \text{ A}; \text{ dI}_{com}/\text{dt} = 7.2 \text{ A/ms}; \text{ gate open circuit}$	10	20	-	V/µs
t _{gt}	Gate controlled turn-on time	$I_{TM} = 20 \text{ A}; V_D = V_{DRM(max)}; I_G = 0.1 \text{ A};$ $dI_G/dt = 5 \text{ A}/\mu\text{s}$	-	2	-	μs

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Triacs high noise immunity

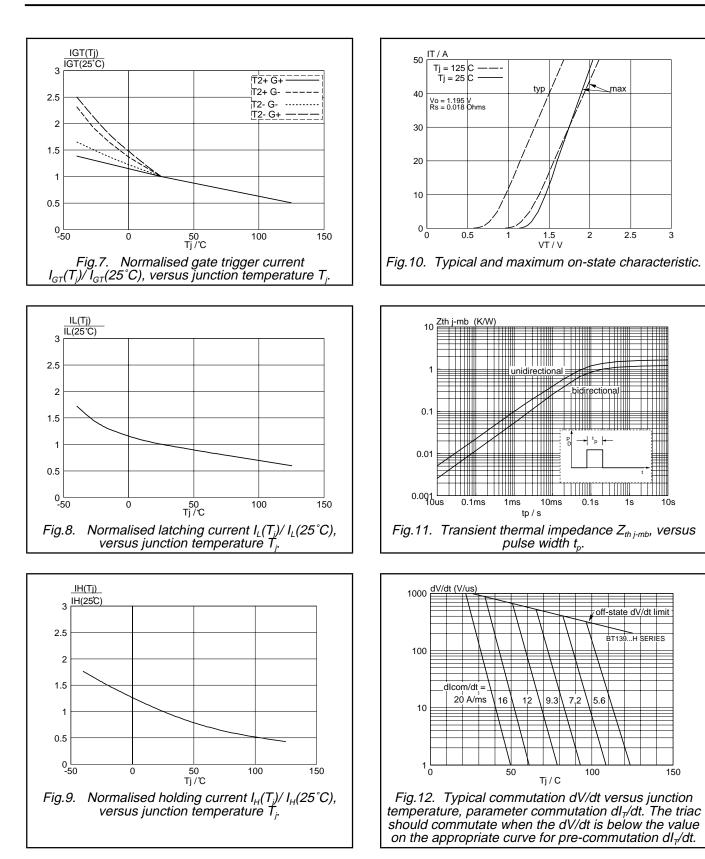
IT(RMS) / A Tmb(max) / C₉₅ Ptot / W 20 25 ∝= 180 99°C 20 01 120 15 90 107 15 60 10 30 10 13 5 5 119 ___125 20 0 0 -50 5 10 IT(RMS) / A 15 0 50 Tmb / C 100 150 Fig.1. Maximum on-state dissipation, P_{tot} , versus rms on-state current, $I_{T(RMS)}$, where α = conduction angle. Fig.4. Maximum permissible rms current $I_{T(RMS)}$, versus mounting base temperature T_{mb} . IT(RMS) / A ITSM / / 1000 50 40 30 100 dl_T/dt limit 20 G+ quadrant 10 may 10 L 10us 8.01 100us 1ms 10ms 100ms 0.1 10 surge duration / s T/s Fig.2. Maximum permissible non-repetitive peak Fig.5. Maximum permissible repetitive rms on-state on-state current I_{TSM} , versus pulse width t_p , for sinusoidal currents, $t_p \le 20ms$. current I_{T(RMS)}, versus surge duration, for sinusoidal currents, f = 50 Hz; $T_{mb} \le 99$ °C. VGT(Tj) ITSM 150 VGT(25°C 1.6 ITSM 1.4 time 100 25°C ma 1.2 1 50 0.8 0.6 0.4 <u>-</u>50 0





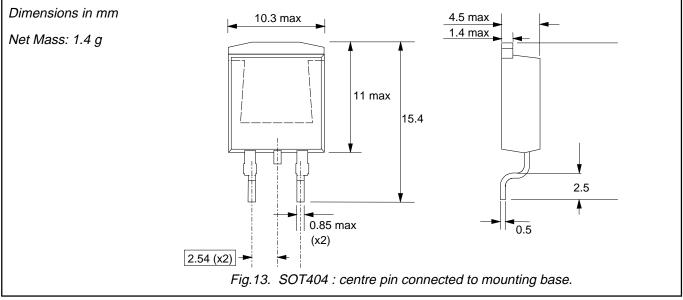
 $V_{GT}(T_i)/V_{GT}(25^{\circ}C)$, versus junction temperature T_i .

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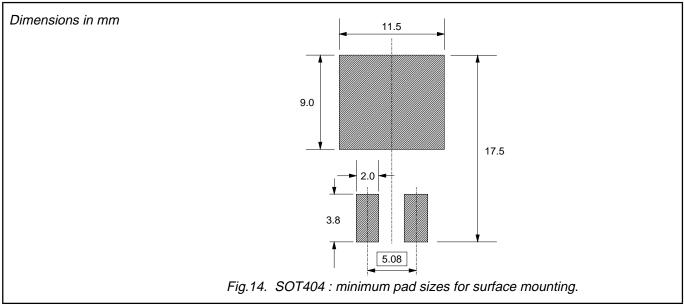
MECHANICAL DATA



Notes

1. Epoxy meets UL94 V0 at 1/8".

MOUNTING INSTRUCTIONS



Notes

1. Plastic meets UL94 V0 at 1/8".

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DEFINITIONS

Data sheet status					
Objective specification	This data sheet contains target or goal specifications for product development.				
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.				
Product specification	This data sheet contains final product specifications.				

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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